

DATA SHEET

74ALVCH16952

16-bit registered transceiver (3-State)

Preliminary specification
Supersedes data of 1994 Jul
IC24 Data Handbook

1998 Sep 01

16-bit registered transceiver (3-State)

74ALVCH16952

FEATURES

- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- MULTIBYTE™ flow-through pin-out architecture
- Low inductance, multiple center power and ground pins for minimum noise and ground bounce
- Direct interface with TTL levels
- Output drive capability 50Ω transmission lines @ 85°C

DESCRIPTION

The 74ALVCH16952 consists of two sections, each containing a dual octal non-inverting registered transceiver. Two 8-bit back to back registers store data flowing in both directions between two bi-directional busses. Data applied to the inputs is entered and stored on the rising edge of the clock (CP_{XX}, where X is AB or BA) provided that the clock enable (\overline{CE}_{XX}) is LOW. The data is then present at the 3-State output buffers, but is only accessible when the output enable input (\overline{OE}_{XX}) is LOW. Data flow from A inputs to B outputs is the same as for B inputs to A outputs.

QUICK REFERENCE DATA

GND = 0V; T_{amb} = 25°C; t_r = t_f = 2.5ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay CP _n , to An, Bn	V _{CC} = 3.3V, C _L = 50pF V _{CC} = 2.5V, C _L = 30pF	3.2	ns
f _{MAX}	Maximum clock frequency		350	MHz
C _I	Input capacitance		3.0	pF
C _{PD}	Power dissipation capacitance per buffer	V _I = GND to V _{CC} ¹	30	pF

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz; C_L = output load capacity in pF;

f_o = output frequency in MHz; V_{CC} = supply voltage in V;

$\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
56-Pin Plastic TSSOP Type II	-40°C to +85°C	74ALVCH16952 DGG	ACH16952 DGG	SOT364-1

FUNCTION TABLE for register An or Bn

INPUTS			INTERNAL Q	OPERATING MODE
An or Bn	CP _{XX}	\overline{CE}_{XX}		
X	X	H	NC	Hold data
L	↑	L	L	Load data
H	↑	L	H	Load data

H = HIGH voltage level

L = LOW voltage level

↑ = LOW-to-HIGH transition

FUNCTION TABLE for output enable

INPUTS	INTERNAL Q	An or Bn OUTPUTS	OPERATING MODE
\overline{OE}_{nn}			
H	X	Z	Disable outputs
L	L	L	Enable outputs
L	H	H	Enable outputs

NC = no change

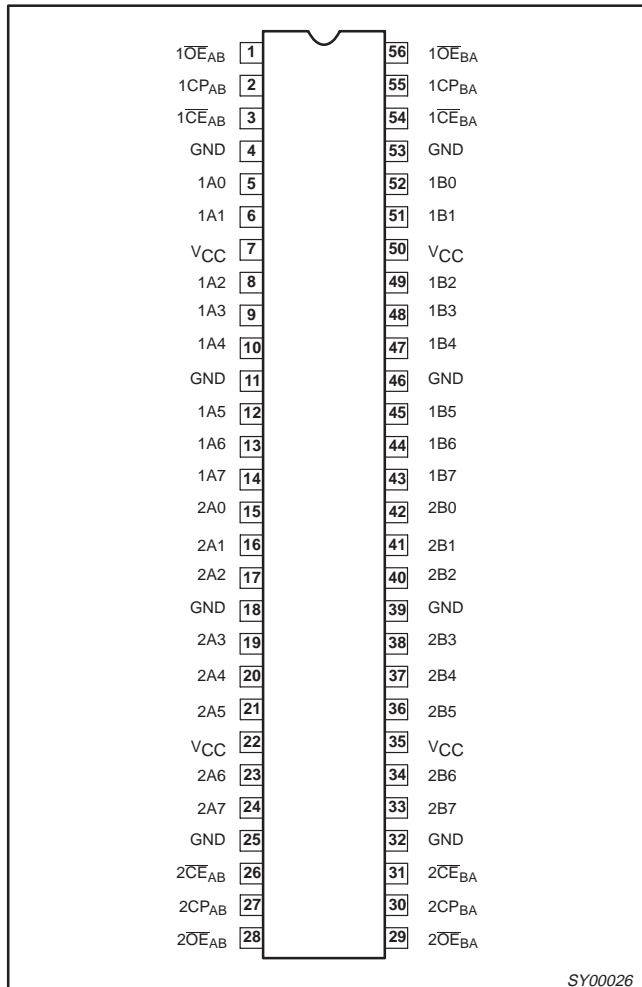
X = don't care

Z = high impedance OFF-state

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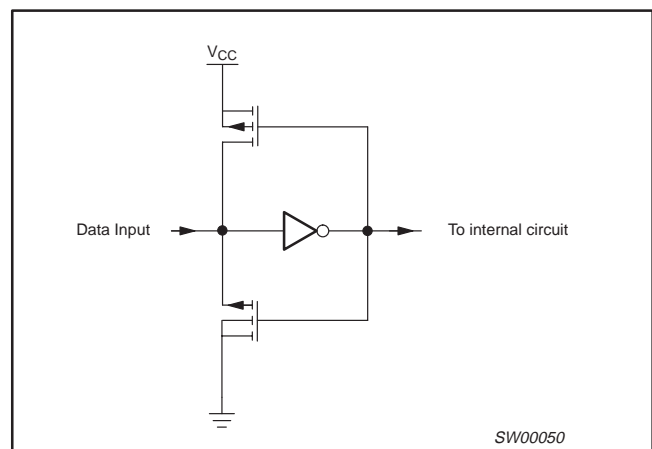
PIN CONFIGURATION



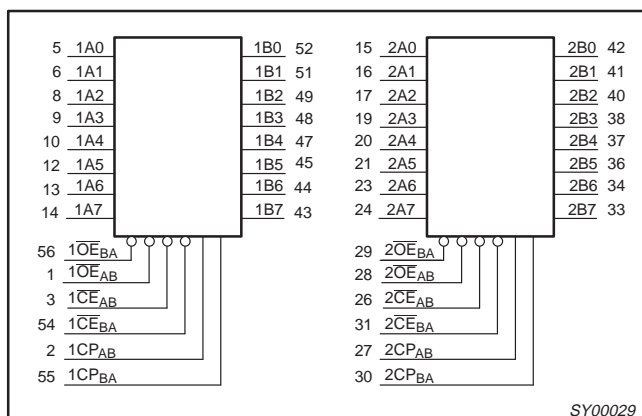
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 28	\overline{nOE}_{AB}	Output enable A-to-B
2, 27	\overline{nCP}_{AB}	Clock input A-to-B
3, 26	\overline{nCE}_{AB}	A-to-B enable
5, 6, 8, 9, 10, 12, 13, 14	1A0 to 1A7	Data inputs/outputs
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage
15, 16, 17, 19, 20, 21, 23, 24	2B0 to 2B7	Data inputs/outputs
29, 56	\overline{nOE}_{BA}	Output enable B-to-A
30, 55	\overline{nCP}_{BA}	Clock input B-to-A
31, 54	\overline{nCE}_{BA}	B-to-A enable
42, 41, 40, 38, 37, 36, 34, 33	2B0 to 2B7	Data inputs/outputs
52, 51, 49, 48, 47, 45, 44, 43	1B0 to 1B7	Data inputs/outputs

BUSHOLD CIRCUIT



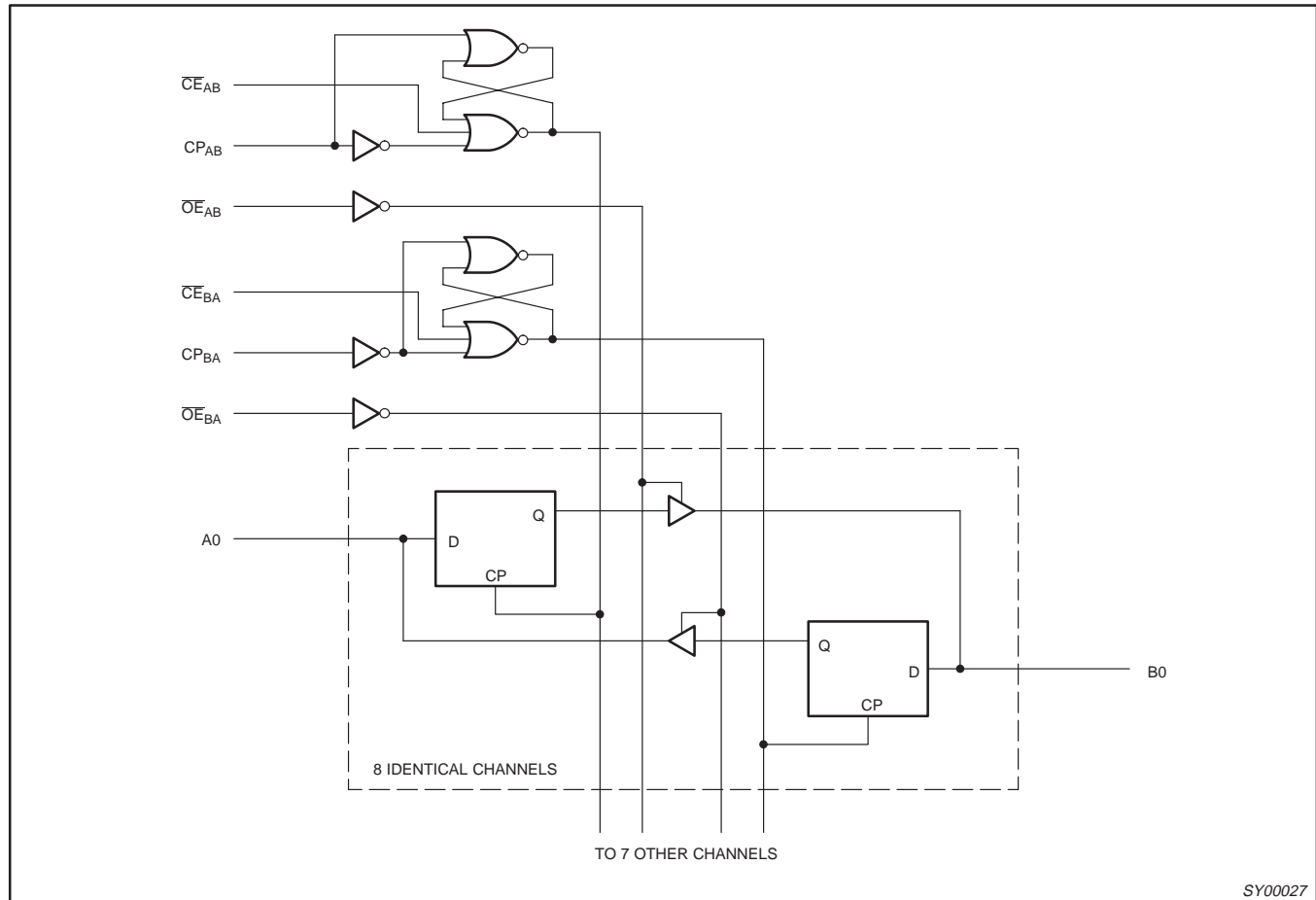
LOGIC SYMBOL



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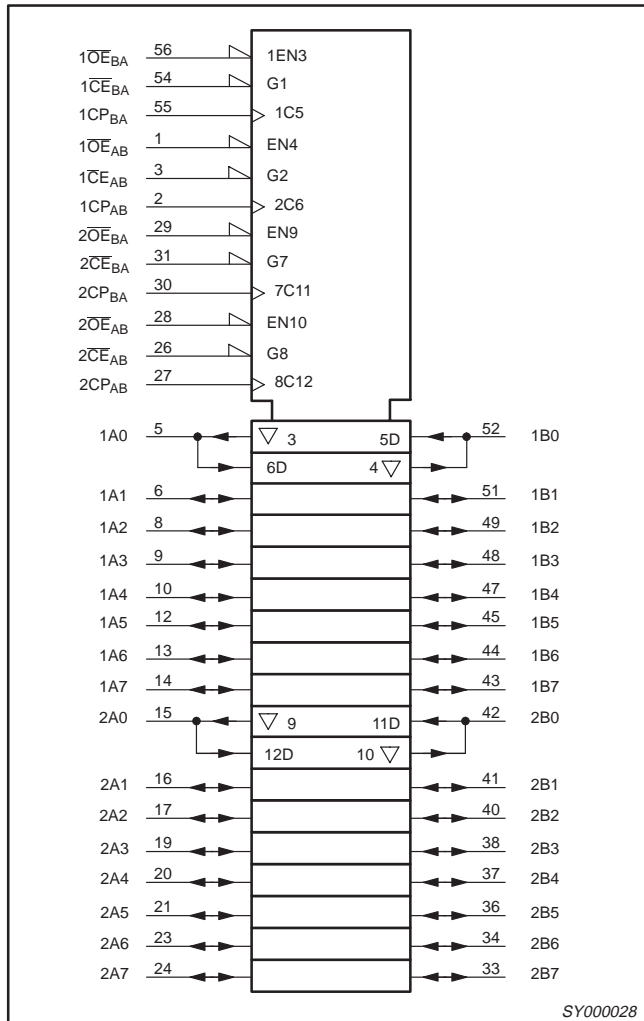
LOGIC SYMBOL (one section)



16-bit registered transceiver (3-State)

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LOGIC SYMBOL (IEEE/IEC)



16-bit registered transceiver (3-State)

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIMITS		UNIT
			MIN	MAX	
V_{CC}	DC supply voltage 2.5V range (for max. speed performance @ 30 pF output load)		2.3	2.7	V
	DC supply voltage 3.3V range (for max. speed performance @ 50 pF output load)		3.0	3.6	
V_I	DC Input voltage range		0	V_{CC}	V
V_O	DC output voltage range		0	V_{CC}	V
T_{amb}	Operating free-air temperature range		-40	+85	°C
t_r, t_f	Input rise and fall times	$V_{CC} = 2.3$ to $3.0V$	0	20	ns/V
		$V_{CC} = 3.0$ to $3.6V$	0	10	

ABSOLUTE MAXIMUM RATINGS

In accordance with the Absolute Maximum Rating System (IEC 134)

Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to +4.6	V
I_{IK}	DC input diode current	$V_I < 0$	-50	mA
V_I	DC input voltage	For control pins ¹	-0.5 to +4.6	V
		For data inputs ¹	-0.5 to $V_{CC} + 0.5$	
I_{OK}	DC output diode current	$V_O > V_{CC}$ or $V_O < 0$	±50	mA
V_O	DC output voltage	Note 1	-0.5 to $V_{CC} + 0.5$	V
I_O	DC output source or sink current	$V_O = 0$ to V_{CC}	±50	mA
I_{GND}, I_{CC}	DC V_{CC} or GND current		±100	mA
T_{stg}	Storage temperature range		-65 to +150	°C
P_{TOT}	Power dissipation per package –plastic medium-shrink (SSOP) –plastic thin-medium-shrink (TSSOP)	For temperature range: -40 to +125 °C	850	mW
		above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	600	

NOTE:

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Temp = -40°C to +85°C			
			MIN	TYP ¹	MAX	
V _{IH}	HIGH level Input voltage	V _{CC} = 2.3 to 2.7V	1.7	1.2		V
		V _{CC} = 2.7 to 3.6V	2.0	1.5		
V _{IL}	LOW level Input voltage	V _{CC} = 2.3 to 2.7V		1.2	0.7	V
		V _{CC} = 2.7 to 3.6V		1.5	0.8	
V _{OH}	HIGH level output voltage	V _{CC} = 2.3 to 3.6V; V _I = V _{IH} or V _{IL} ; I _O = -100μA	V _{CC} - 0.2	V _{CC}		V
		V _{CC} = 2.3V; V _I = V _{IH} or V _{IL} ; I _O = -6mA	V _{CC} - 0.3	V _{CC} - 0.08		
		V _{CC} = 2.3V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.6	V _{CC} - 0.26		
		V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.5	V _{CC} - 0.14		
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.6	V _{CC} - 0.09		
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -24mA	V _{CC} - 1.0	V _{CC} - 0.28		
V _{OL}	LOW level output voltage	V _{CC} = 2.3 to 3.6V; V _I = V _{IH} or V _{IL} ; I _O = 100μA		GND	0.20	V
		V _{CC} = 2.3V; V _I = V _{IH} or V _{IL} ; I _O = 6mA		0.07	0.40	V
		V _{CC} = 2.3V; V _I = V _{IH} or V _{IL} ; I _O = 12mA		0.15	0.70	V
		V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = 12mA		0.14	0.40	
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 24mA		0.27	0.55	
I _I	Input leakage current	V _{CC} = 2.3 to 3.6V; V _I = V _{CC} or GND		0.1	5	μA
I _{OZ}	3-State output OFF-state current	V _{CC} = 2.7 to 3.6V; V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND		0.1	10	μA
I _{CC}	Quiescent supply current	V _{CC} = 2.3 to 3.6V; V _I = V _{CC} or GND; I _O = 0		0.2	40	μA
ΔI _{CC}	Additional quiescent supply current	V _{CC} = 2.3V to 3.6V; V _I = V _{CC} - 0.6V; I _O = 0		150	750	μA
I _{BHL}	Bus hold LOW sustaining current	V _{CC} = 2.3V; V _I = 0.7V ²	45	-		μA
		V _{CC} = 3.0V; V _I = 0.8V ²	75	150		
I _{BHH}	Bus hold HIGH sustaining current	V _{CC} = 2.3V; V _I = 1.7V ²	-45			μA
		V _{CC} = 3.0V; V _I = 2.0V ²	-75	-175		
I _{BHLO}	Bus hold LOW overdrive current	V _{CC} = 3.6V ²	500			μA
I _{BHHO}	Bus hold HIGH overdrive current	V _{CC} = 3.6V ²	-500			μA

NOTES:

1. All typical values are at T_{amb} = 25°C.
2. Valid for data inputs of bus hold parts.

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AC CHARACTERISTICS FOR $V_{CC} = 2.3V$ TO $2.7V$ RANGEGND = 0V; $t_r = t_f \leq 2.0ns$; $C_L = 30pF$

SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT
			$V_{CC} = 2.5V \pm 0.2V$			
			MIN	TYP	MAX	
t_{PLH}/t_{PHL}	Propagation delay nCP _{AB} to nBn, nCP _{BA} to nAn	3	1.0		4.1	ns
t_{PZH}/t_{PZL}	3-State output enable time nOE to nAn, nBn	4	1.0		5.4	ns
t_{PHZ}/t_{PLZ}	3-State output disable time nOE to nAn, nBn	4	1.0		5.3	ns
t_W	Pulse width HIGH or LOW nCP _{AB} , nCP _{BA}	3	3.3			ns
t_{SU}	Set up time An or Bn before CP _{AB}	3	1.7			ns
	Set up time CE _{AB} or CE _{BA} before CP _{AB}	3	1.2			
t_h	Hold time An or Bn after CP _{AB}	3	0.6			ns
	Hold time An or Bn after CP _{AB}	3	1.1			
F_{max}	Maximum clock pulse frequency	3	150			MHz

NOTE:1. All typical values are at $V_{CC} = 2.5V$ and $T_{amb} = 25^\circ C$.**AC CHARACTERISTICS FOR $V_{CC} = 3.0V$ TO $3.6V$ RANGE AND $V_{CC} = 2.7V$** GND = 0V; $t_r = t_f = 2.5ns$; $C_L = 50pF$

SYMBOL	PARAMETER	WAVEFORM	LIMITS						UNIT
			$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$			
			MIN	TYP ^{1, 2}	MAX	MIN	TYP ¹	MAX	
t_{PHL}/t_{PLH}	Propagation delay nCP _{AB} to nBn, nCP _{BA} to nAn	1, 4	1.0		3.9	1.0		4.6	ns
t_{PZH}/t_{PZL}	3-State output enable time nOE to nAn, nBn	2, 4	1.0		4.4	1.0		5.3	ns
t_{PHZ}/t_{PLZ}	3-State output disable time nOE to nAn, nBn	2, 4	1.1		4	1.4		4.4	ns
t_W	Pulse width HIGH or LOW nCP _{AB} , nCP _{BA}	3, 4	3.3			3.3			ns
t_{SU}	Set up time An or Bn before CP _{AB}	3, 4	1.5			1.9			ns
	Set up time CE _{AB} or CE _{BA} before CP _{AB}	3, 4	1			1			
t_h	Hold time An or Bn after CP _{AB}	3, 4	0.8			0.6			ns
	Hold time An or Bn after CP _{AB}	3, 4	1.1			0.9			
F_{max}	Maximum clock pulse frequency	1, 4	150			150			MHz

NOTES:1. All typical values are at $T_{amb} = 25^\circ C$.2. $V_{CC} = 3.3V$

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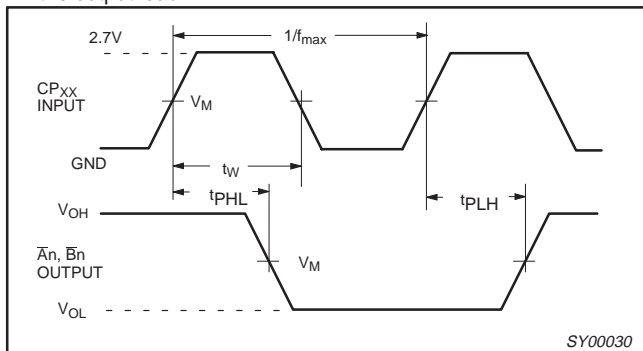
AC WAVEFORMS

V_{CC} = 2.3 TO 2.7 V RANGE

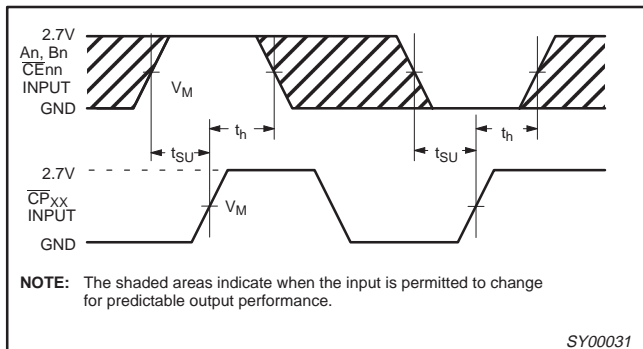
1. V_M = 0.5 V
2. V_X = V_{OL} + 0.15V
3. V_Y = V_{OH} - 0.15V
4. V_I = V_{CC}
5. V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

V_{CC} = 3.0 TO 3.6 V RANGE AND V_{CC} = 2.7 V

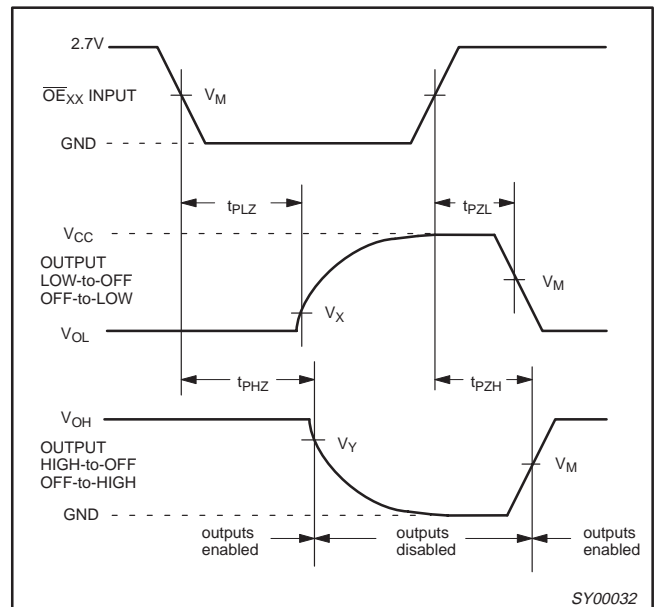
1. V_M = 1.5 V
2. V_X = V_{OL} + 0.3V
3. V_Y = V_{OH} - 0.3V
4. V_I = 2.7 V
5. V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.



Waveform 1. Clock input (CP_{BA}, CP_{AB}) to output (B_n, A_n) propagation delays, the clock pulse width and the maximum clock pulse frequency.

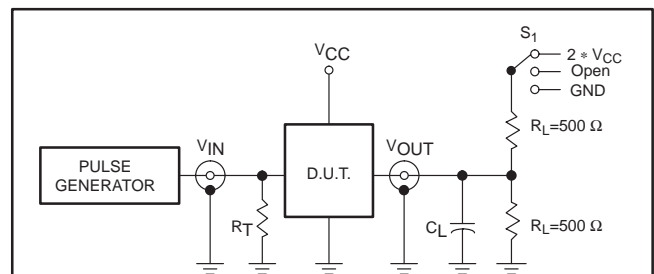


Waveform 2. Set-up and hold times for the A_n, B_n and C_E_{XX} inputs.



Waveform 3. 3-State enable and disable times

TEST CIRCUIT



Test Circuit for 3-State Outputs

SWITCH POSITION

TEST	SWITCH
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	2 * V _{CC}
t _{PHZ} /t _{PZH}	GND

V _{CC}	V _{IN}
< 2.7V	V _{CC}
2.7 – 3.6V	2.7V

DEFINITIONS

- R_L = Load resistor
- C_L = Load capacitance includes jig and probe capacitance
- R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

SW00047

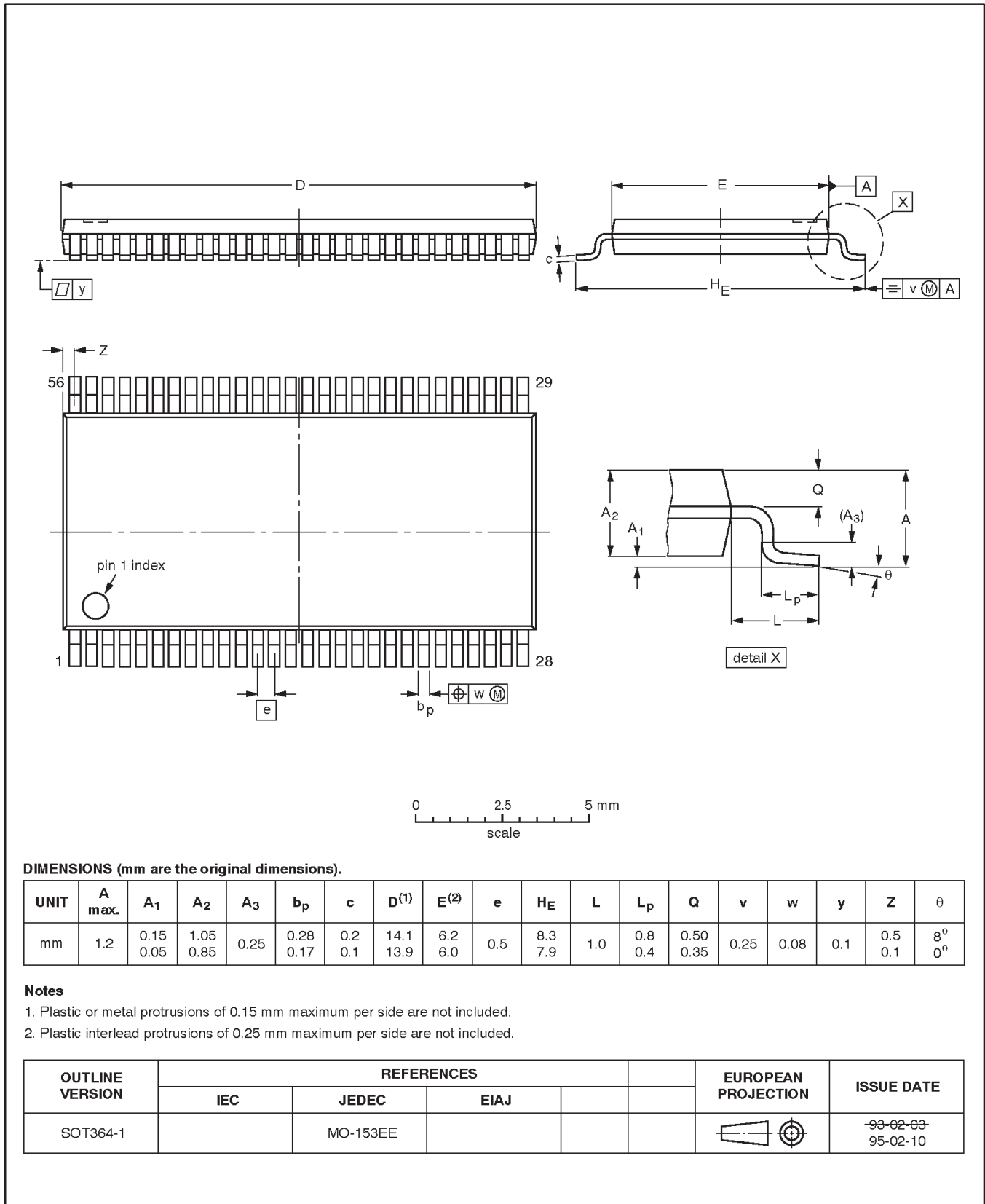
Load circuitry for switching times

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TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1mm

SOT364-1



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NOTES

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DEFINITIONS

Data Sheet Identification	Product Status	Definition
<i>Objective Specification</i>	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
<i>Preliminary Specification</i>	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
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